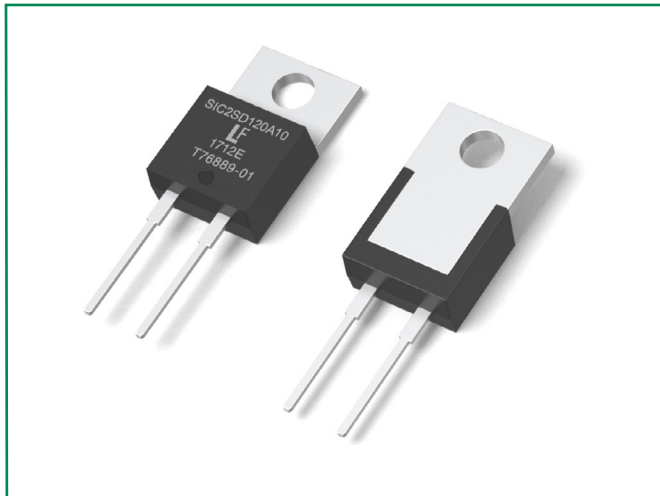


LSIC2SD120A10



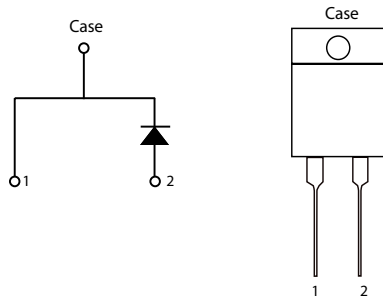
Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

Circuit Diagram TO-220-2L



Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- Solar inverters
- Industrial motor drives
- EV charging stations

Environmental

- Littelfuse "RoHS" logo = RoHS conform
- Littelfuse "HF" logo = **HF** Halogen Free
- Littelfuse "PB-free" logo = PB-free lead plating

Maximum Ratings

Characteristics	Symbol	Conditions	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	-	1200	V
DC Blocking Voltage	V_R	$T_J = 25\text{ °C}$	1200	V
Continuous Forward Current	I_F	$T_C = 25\text{ °C}$	28	A
		$T_C = 125\text{ °C}$	15	
		$T_C = 151\text{ °C}$	10	
Non-Repetitive Forward Surge Current	I_{FSM}	$T_C = 25\text{ °C}, T_P = 10\text{ ms}, \text{Half sine pulse}$	80	A
Power Dissipation	P_{Tot}	$T_C = 25\text{ °C}$	136	W
		$T_C = 110\text{ °C}$	59	
Operating Junction Temperature	T_J	-	-55 to 175	°C
Storage Temperature	T_{STG}	-	-55 to 150	°C
Soldering Temperature	T_{sold}	-	260	°C

Electrical Characteristics

Characteristics	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Forward Voltage	V_F	$I_F = 10\text{ A}, T_J = 25\text{ }^\circ\text{C}$	-	1.5	1.8	V
		$I_F = 10\text{ A}, T_J = 175\text{ }^\circ\text{C}$	-	2.2		
Reverse Current	I_R	$V_R = 1200\text{ V}, T_J = 25\text{ }^\circ\text{C}$	-	<1	100	μA
		$V_R = 1200\text{ V}, T_J = 175\text{ }^\circ\text{C}$	-	10		
Total Capacitance	C	$V_R = 1\text{ V}, f = 1\text{ MHz}$	-	582		pF
		$V_R = 400\text{ V}, f = 1\text{ MHz}$	-	53		
		$V_R = 800\text{ V}, f = 1\text{ MHz}$	-	40		
Total Capacitive Charge	Q_C	$V_R = 800\text{ V}, Q_C = \int_0^{V_R} C(V) dV$	-	57		nC

Footnote: $T_J = +25\text{ }^\circ\text{C}$ unless otherwise specified

Thermal Characteristics

Characteristics	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Thermal Resistance	$R_{\theta JC}$	-	-	1.1		$^\circ\text{C}/\text{W}$

Figure 1: Typical Forward Characteristics

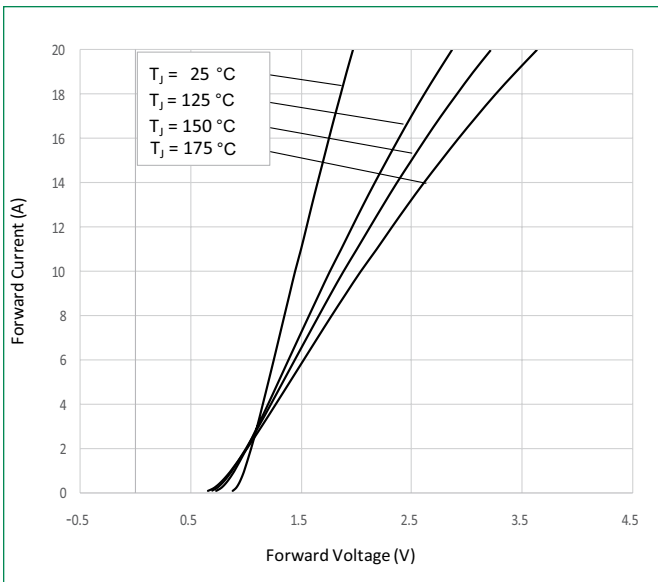


Figure 2: Typical Reverse Characteristics

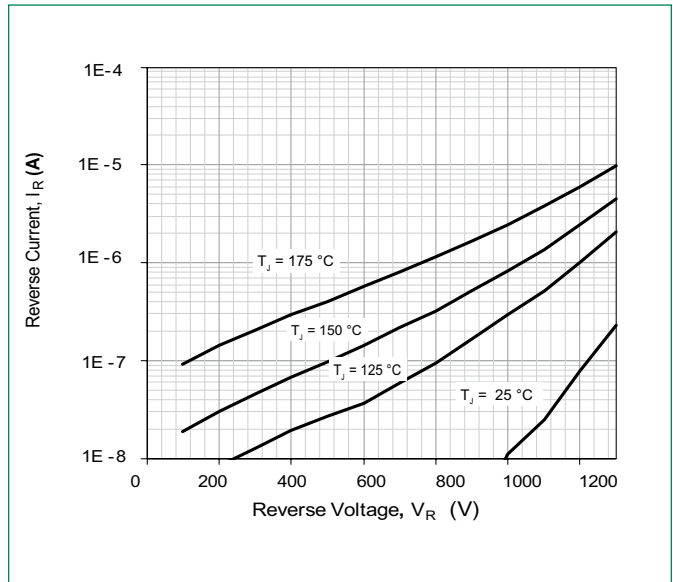


Figure 3: Power Derating

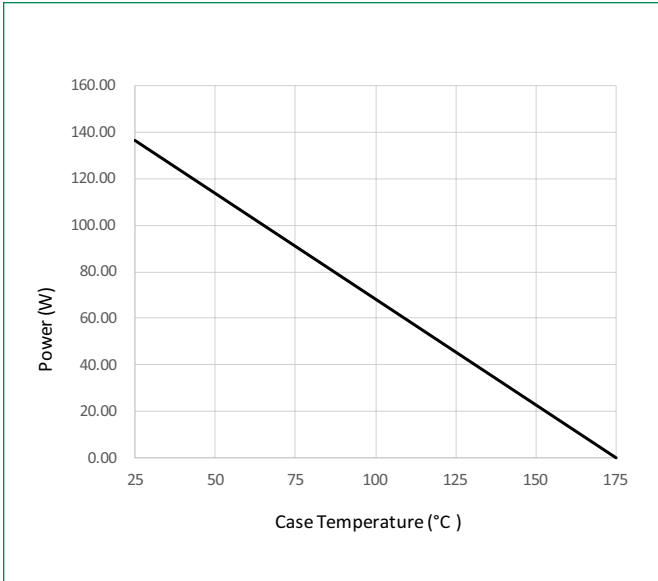


Figure 4: Current Derating

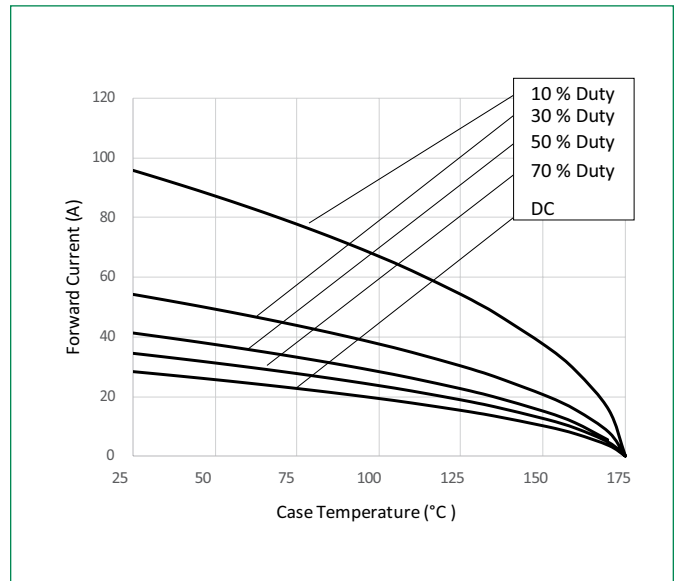


Figure 5: Capacitance vs. Reverse Voltage

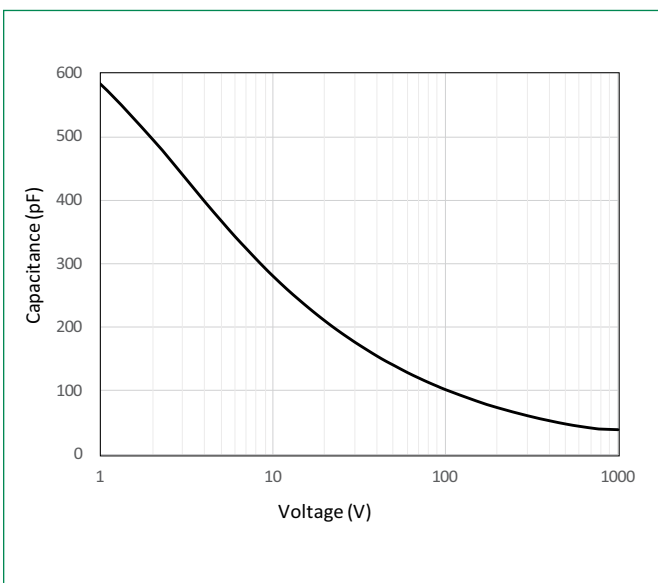


Figure 6: Capacitive Charge vs. Reverse Voltage

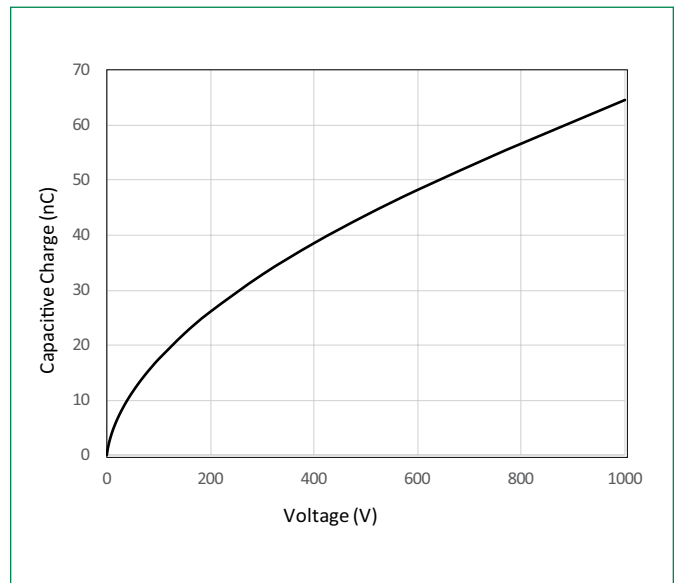


Figure 7: Stored Energy vs. Reverse Voltage

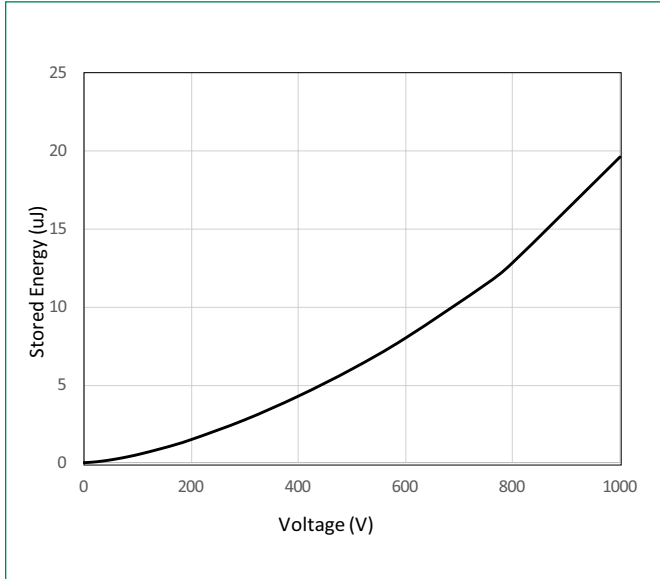
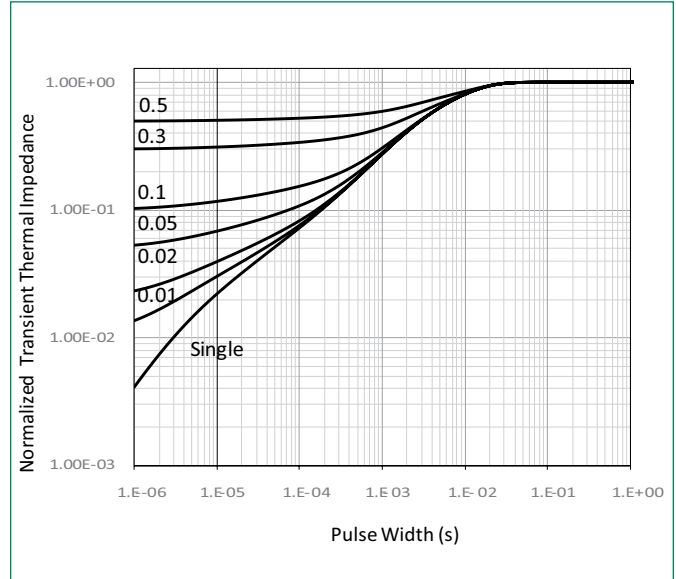
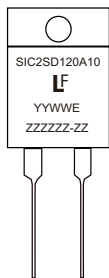


Figure 8: Transient Thermal Impedance



Part Numbering and Marking System

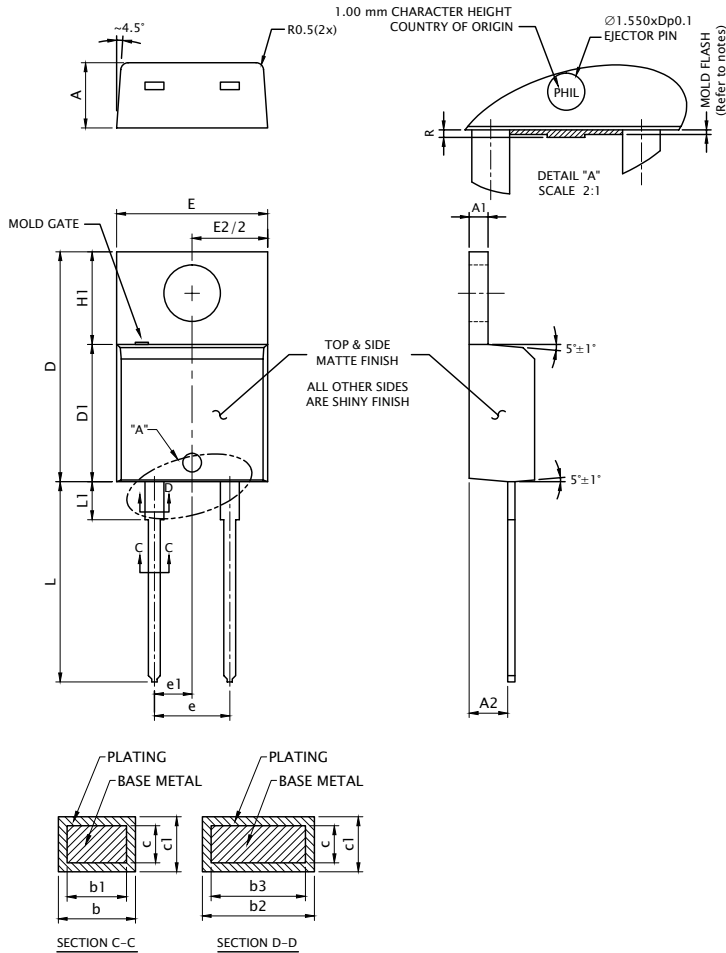


- SIC = SiC Diode
- 2 = Gen2
- SD = Schottky Diode
- 120 = Voltage Rating (1200 V)
- A = TO-220-2L
- 10 = Current Rating (10 A)
- YY = Year
- WW = Week
- E = Special Code
- ZZZZZ-ZZ = Lot Number

Packing Options

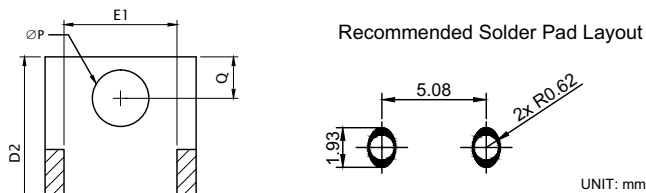
Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD120A10	SIC2SD120A10	Tube	1000

Dimensions-Package TO-220-2L



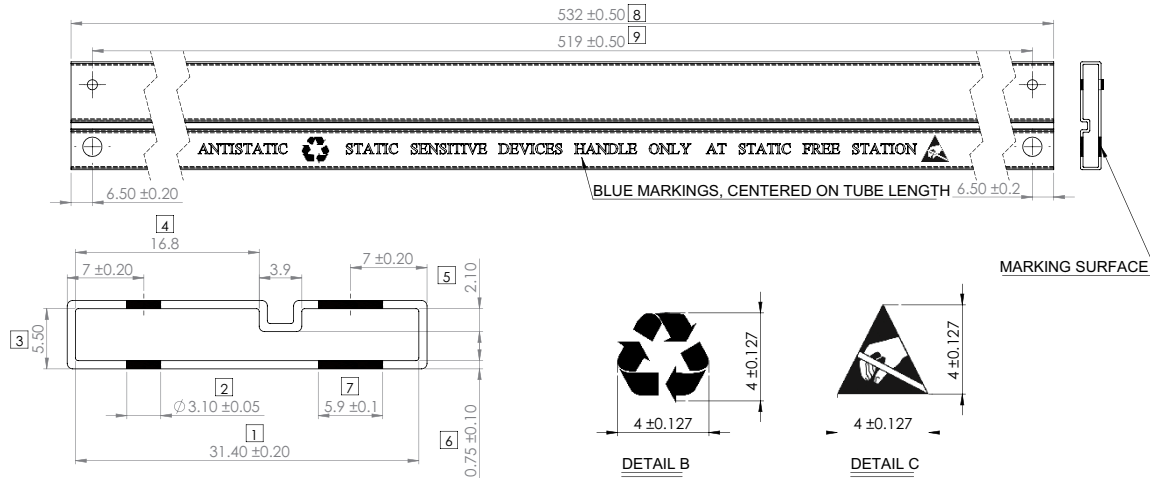
Symbol	Millimeters		
	Min	Nominal	Max
A	4.320	4.450	4.570
A1	1.140	1.270	1.400
A2	2.500	-	2.740
b	0.690	-	0.880
b1	0.680	-	0.870
b2	1.230	-	1.390
b3	1.220	1.270	1.380
c	0.360	-	0.503
c1	0.630	-	0.527
D	14.900	-	15.600
D1	8.615	-	9.017
D2	12.840	-	12.950
E	10.000	10.180	10.360
E1	7.570	7.610	7.680
e1	2.490	2.540	2.590
e	5.030	5.080	5.130
H1	6.295	6.545	6.795
L	13.000	13.500	14.00
L1	2.390	-	3.250
øP	3.710	3.840	3.960
Q	2.650	-	3.050
R	-	-	0.254

Recommended Solder Pad Layout



- NOTES:
1. DIMENSIONS D & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.127 MM PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTERMOST EXTREME OF PLASTIC BODY.
 2. DIMENSIONS E2 & H1 DEFINE A ZONE WHERE STAMPING AND SINGULATION IRREGULARITIES RE ALLOWED.

Packing Specification (Tube for TO-220-2L)



- NOTES:
1. Material transparent extruded PVC with antistatic dipping
 2. Radius : 0.5 maximum unless otherwise specified
 3. Critical areas : Labelled in Box
 4. All pin plug holes are considered critical dimension
 5. Marking Font Type : Times new roman, 3.12 ± 0.127 in height
 6. Material Thickness : 0.75 ± 0.10
 7. Tolerance unless otherwise specified: Decimal: ±0.05 Angle: ±1°
 8. Unit : Millimeter (mm)

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